

SNAS310D - JANUARY 2006 - REVISED JANUARY 2014

# ADC081S101 Single Channel, 0.5 to 1 Msps, 8-Bit A/D Converter

Check for Samples: ADC081S101

## **FEATURES**

- Specified Over a Range of Sample Rates.
- 6-Lead WSON and SOT-23 Packages
- Variable Power Management
- Single Power Supply with 2.7V 5.25V Range
- SPI™/QSPI™/MICROWIRE/DSP Compatible

# **APPLICATIONS**

- Portable Systems
- **Remote Data Aquisitions**
- Instrumentation and Control Systems

# **KEY SPECIFICATIONS**

- $DNL \pm 0.07 LSB (typ)$
- INL  $\pm$  0.05 LSB (typ)
- SNR 49.7 dB (typ)
- **Power Consumption** 
  - 3V Supply 2.0 mW (typ)
  - 5V Supply 10.0 mW (typ)

## DESCRIPTION

The ADC081S101 is a low-power, single channel CMOS 8-bit analog-to-digital converter with a highspeed serial interface. Unlike the conventional practice of specifying performance at a single sample rate only, the ADC081S101 is fully specified over a sample rate range of 500 ksps to 1 Msps. The converter is based upon a successive-approximation register architecture with an internal track-and-hold circuit.

The output serial data is straight binary, and is compatible with several standards, such as SPI™, QSPI™, MICROWIRE, and many common DSP serial interfaces.

The ADC081S101 operates with a single supply that can range from +2.7V to +5.25V. Normal power consumption using a +3V or +5V supply is 2.0 mW and 10.0 mW, respectively. The power-down feature reduces the power consumption to just 2.5 µW using a +5V supply.

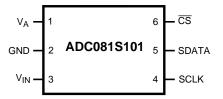
The ADC081S101 is packaged in an 6-lead WSON and SOT-23 packages. Operation over the industrial temperature range of -40°C to +85°C is ensured.

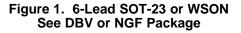
## Table 1. Pin-Compatible Alternatives by Resolution and Speed<sup>(1)</sup>

Resolution	Specified for Sample Rate Range of:								
	50 to 200 ksps	200 to 500 ksps	500 ksps to 1 Msps						
12-bit	ADC121S021	ADC121S051	ADC121S101						
10-bit	ADC101S021	ADC101S051	ADC101S101						
8-bit	ADC081S021	ADC081S051	ADC081S101						

(1) All devices are fully pin and function compatible.

## Connection Diagram





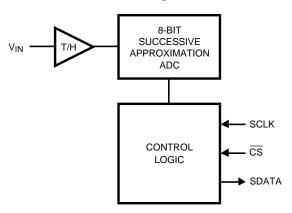


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### Block Diagram



### PIN DESCRIPTIONS AND EQUIVALENT CIRCUITS

Pin No.	Symbol Description							
ANALOG I/C	)							
3	V <sub>IN</sub>	Analog input. This signal can range from 0V to V <sub>A</sub> .						
DIGITAL I/O								
4	SCLK	Digital clock input. This clock directly controls the conversion and readout processes.						
5	SDATA	Digital data output. The output samples are clocked out of this pin on falling edges of the SCLK pin.						
6	CS	Chip select. On the falling edge of $\overline{CS}$ , a conversion process begins.						
POWER SU	PPLY							
1	V <sub>A</sub>	Positive supply pin. This pin should be connected to a quiet +2.7V to +5.25V source and bypassed to GND with a 1 $\mu$ F capacitor and a 0.1 $\mu$ F monolithic capacitor located within 1 cm of the power pin.						
2	GND	The ground return for the supply and signals.						
PAD	GND	For package suffix CISD(X) only, it is recommended that the center pad should be connected to ground.						



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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### Absolute Maximum Ratings (1)(2)(3)

-0.3V to 6.5V
-0.3V to (V <sub>A</sub> +0.3)V
±10 mA
±20 mA
See <sup>(5)</sup>
3500V 300V
+150°C
-65°C to +150°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) All voltages are measured with respect to GND = 0V, unless otherwise specified.
- (4) When the input voltage at any pin exceeds the power supply (that is, V<sub>IN</sub> < GND or V<sub>IN</sub> > V<sub>A</sub>), the current at that pin should be limited to 10 mA. The 20 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 10 mA to two. The Absolute Maximum Rating specification does not apply to the V<sub>A</sub> pin. The current into the V<sub>A</sub> pin is limited by the Analog Supply Voltage specification.
- (5) The absolute maximum junction temperature ( $T_Jmax$ ) for this device is 150°C. The maximum allowable power dissipation is dictated by  $T_Jmax$ , the junction-to-ambient thermal resistance ( $\theta_{JA}$ ), and the ambient temperature ( $T_A$ ), and can be calculated using the formula  $P_Dmax = (T_Jmax T_A) / \theta_{JA}$ . The values for maximum power dissipation listed above will be reached only when the device is operated in a severe fault condition (e.g. when input or output pins are driven beyond the power supply voltages, or the power supply polarity is reversed). Obviously, such conditions should always be avoided.
- (6) Human body model is 100 pF capacitor discharged through a 1.5 k $\Omega$  resistor. Machine model is 220 pF discharged through zero ohms.

### Operating Ratings (1)(2)

Operating Temperature Range	-40°C ≤ T <sub>A</sub> ≤ +85°C
V <sub>A</sub> Supply Voltage	+2.7V to +5.25V
Digital Input Pins Voltage Range (regardless of supply voltage)	-0.3V to +5.25V
Clock Frequency	25 kHz to 20 MHz
Sample Rate	Up to 1 Msps
Analog Input Voltage	0V to V <sub>A</sub>

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(2) All voltages are measured with respect to GND = 0V, unless otherwise specified.

### Package Thermal Resistance<sup>(1)</sup>

Package	θ <sub>JA</sub>
6-lead WSON	94°C / W
6-lead SOT-23	265°C / W

Soldering process must comply with Texas Instrument's Reflow Temperature Profile specifications. Refer to www.ti.com and http://www.ti.com/lit/SNOA549.

(1) Reflow temperature profiles are different for lead-free and non-lead-free packages.

# ADC081S101 Converter Electrical Characteristics <sup>(1)(2)</sup>

The following specifications apply for  $V_A = +2.7V$  to 5.25V, GND = 0V,  $f_{SCLK} = 10$  MHz to 20 MHz,  $C_L = 15$  pF,  $f_{SAMPLE} = 500$  ksps to 1 Msps, unless otherwise noted. **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}: all other limits T\_A = 25^{\circ}C.** 

Symbol	Parameter	Conditions	Typical	Limits	Units			
STATIC CO	ONVERTER CHARACTERIST	CS	1 1					
	Resolution with No Missing Codes			8	Bits			
INL	Integral Non-Linearity	V <sub>A</sub> = +2.7V to +5.25V	±0.05	±0.3	LSB (max)			
DNL	Differential Non-Linearity	V <sub>A</sub> = +2.7V to +5.25V	±0.07	±0.3	LSB (max)			
V <sub>OFF</sub>	Offset Error	V <sub>A</sub> = +2.7V to +5.25V	±0.03	±0.3	LSB (max)			
GE	Gain Error	V <sub>A</sub> = +2.7V to +5.25V	±0.08	±0.4	LSB (max)			
TUE	Total Unadjusted Error	V <sub>A</sub> = +2.7V to +5.25V	±0.07	±0.3	LSB (max)			
DYNAMIC	CONVERTER CHARACTERIS	STICS						
SINAD	Signal-to-Noise Plus Distortion Ratio	$V_A$ = +2.7 to 5.25V f <sub>IN</sub> = 100 kHz, -0.02 dBFS	49.7	49	dB (min)			
SNR	Signal-to-Noise Ratio	$V_A$ = +2.7 to 5.25V f <sub>IN</sub> = 100 kHz, -0.02 dBFS	49.7		dB (min)			
THD	Total Harmonic Distortion	$V_A$ = +2.7 to 5.25V f <sub>IN</sub> = 100 kHz, -0.02 dBFS						
SFDR	Spurious-Free Dynamic Range	$V_A$ = +2.7 to 5.25V f <sub>IN</sub> = 100 kHz, -0.02 dBFS	65	dB (min)				
ENOB	Effective Number of Bits	$V_A = +2.7 \text{ to } 5.25 \text{V}$ $f_{\text{IN}} = 100 \text{ kHz}, -0.02 \text{ dBFS}$	7.8	Bits (min)				
IMD	Intermodulation Distortion, Second Order Terms	V <sub>A</sub> = +5.25V f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-68		dB			
	Intermodulation Distortion, Third Order Terms	V <sub>A</sub> = +5.25V f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-68		dB			
FPBW	-3 dB Full Power Bandwidth	$V_A = +5V$	11		MHz			
FFDW		$V_A = +3V$	8		MHz			
ANALOG I	NPUT CHARACTERISTICS							
V <sub>IN</sub>	Input Range		0 to V <sub>A</sub>		V			
I <sub>DCL</sub>	DC Leakage Current			±1	µA (max)			
C <sub>INA</sub>	Input Capacitance	Track Mode	30		pF			
	input oupdolidilitie	Hold Mode	4		pF			
DIGITAL IN	IPUT CHARACTERISTICS	1						
V <sub>IH</sub>	Input High Voltage	V <sub>A</sub> = +5.25V		2.4	V (min)			
• 10	inpartingir renage	V <sub>A</sub> = +3.6V		2.1	( /			
V <sub>IL</sub>	Input Low Voltage	V <sub>A</sub> = +5V		0.8	V (max)			
• 12	, ,	$V_A = +3V$		0.4	V (max)			
I <sub>IN</sub>	Input Current	$V_{IN} = 0V \text{ or } V_A$	±10 nA	±1	µA (max)			
CIND	Digital Input Capacitance		2	4	pF (max)			
DIGITAL O	UTPUT CHARACTERISTICS	1						
V <sub>OH</sub>	Output High Voltage	I <sub>SOURCE</sub> = 200 μA	V <sub>A</sub> - 0.07	V <sub>A</sub> – 0.2	V (min)			
· UH	- apartigit voltage	I <sub>SOURCE</sub> = 1 mA	V <sub>A</sub> – 0.1		V			
V <sub>OL</sub>	Output Low Voltage	I <sub>SINK</sub> = 200 μA	0.03	0.4	V (max)			
		I <sub>SINK</sub> = 1 mA	0.1		V			

(1) Tested limits are specified to TI's AOQL (Average Outgoing Quality Level).

(2) Data sheet min/max specification limits are ensured by design, test, or statistical analysis.



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# ADC081S101 Converter Electrical Characteristics <sup>(1)(2)</sup> (continued)

The following specifications apply for  $V_A = +2.7V$  to 5.25V, GND = 0V,  $f_{SCLK} = 10$  MHz to 20 MHz,  $C_L = 15$  pF,  $f_{SAMPLE} = 500$  ksps to 1 Msps, unless otherwise noted. **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}: all other limits T\_A = 25^{\circ}C.** 

Symbol	Parameter	Conditions		Typical	Limits	Units
I <sub>OZL</sub> , I <sub>OZH</sub>	TRI-STATE® Leakage Current			±0.1	±10	µA (max)
C <sub>OUT</sub>	TRI-STATE® Output Capacitance			2	4	pF (max)
	Output Coding		Straigh	nt (Natural) I	Binary	
POWER S	UPPLY CHARACTERISTICS	1				I
V <sub>A</sub>	Supply Voltage				2.7	V (min)
			COT 02		5.25	V (max)
		$V_A = +5.25V, f_{SAMPLE} = 1 Msps$	SOT-23	2.0	3.2	mA (max)
	Supply Current, Normal Mode (Operational, CS low)		WSON		2.6	(IIIax)
1.		$V_A = +3.6V$ , $f_{SAMPLE} = 1$ Msps	SOT-23	0.6	1.5	mA (max)
I <sub>A</sub>	A		WSON	500	1.1	. ,
	Supply Current, Shutdown	$V_A = +5.25V$ , $f_{SCLK} = 0$ MHz, $f_{SAMPLE}$	= 0 ksps	500		nA
	(CS high)	$V_A = +5.25V$ , $f_{SCLK} = 20$ MHz, $f_{SAMPLE} = 0$ ksps		60		μΑ
			SOT-23	40	16	mW
Power Consumption, Normal Mode (Operationa CS low) P <sub>D</sub>		V <sub>A</sub> = +5V	WSON	10	13	(max)
		SOT-2	SOT-23	2.0	4.5	mW
	,	$V_A = +3V$	WSON	2.0	3.3	(max)
U	Power Consumption,	$V_A = +5V$ , $f_{SCLK} = 0$ MHz, $f_{SAMPLE} = 0$ ksps	2.5		μW	
	Shutdown (CS high)	$V_A = +5V$ , $f_{SCLK} = 20$ MHz, $f_{SAMPLE} = 0$ ksps		300		μW
AC ELECT	RICAL CHARACTERISTICS	L -				l.
	01 1 5	(3)			10	MHz (min)
f <sub>SCLK</sub>	Clock Frequency			20	MHz (max)	
f <sub>S</sub>	Sample Rate	(3)	50	500	ksps (min)	
'S	Sample Rate				1	Msps (max)
t <sub>HOLD</sub>	Hold Time				13	SCLk Falling Edges
DC	SCLK Duty Cycle	f <sub>SCLK</sub> = 20 MHz		50	40	% (min)
20				50	60	% (max)
t <sub>ACQ</sub>	Minimum Time Required for Acquisition				350	ns (max)
t <sub>QUIET</sub>	(4)				50	ns (min)
t <sub>AD</sub>	Aperture Delay			3		ns
t <sub>AJ</sub>	Aperture Jitter			30		ps

(3) This is the frequency range over which the electrical performance is ensured. The device is functional over a wider range which is specified under Operating Ratings.

(4) Minimum Quiet Time required by bus relinquish and the start of the next conversion.



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## ADC081S101 Timing Specifications

The following specifications apply for  $V_A = +2.7V$  to 5.25V, GND = 0V,  $f_{SCLK} = 10.0$  MHz to 20.0 MHz,  $C_L = 25$  pF,  $f_{SAMPLE} = 500$  ksps to 1 Msps, **Boldface limits apply for T\_A = T\_{MIN} to T\_{MAX}**: all other limits  $T_A = 25^{\circ}C$ .

Symbol	Parameter	Conditions	Typical	Limits	Units
t <sub>CS</sub>	Minimum CS Pulse Width			10	ns (min)
t <sub>SU</sub>	CS to SCLK Setup Time			10	ns (min)
t <sub>EN</sub>	Delay from $\overline{CS}$ Until SDATA TRI-STATE Disabled <sup>(1)</sup>			20	ns (max)
	Data Assess Time often COLK Falling False (2)	V <sub>A</sub> = +2.7 to +3.6		40	ns (max)
t <sub>ACC</sub>	Data Access Time after SCLK Falling Edge <sup>(2)</sup>	V <sub>A</sub> = +4.75 to +5.25		20	ns (max)
t <sub>CL</sub>	SCLK Low Pulse Width			0.4 x t <sub>SCLK</sub>	ns (min)
t <sub>CH</sub>	SCLK High Pulse Width			0.4 x t <sub>SCLK</sub>	ns (min)
		V <sub>A</sub> = +2.7 to +3.6		7	ns (min)
t <sub>H</sub>	SCLK to Data Valid Hold Time	V <sub>A</sub> = +4.75 to +5.25		5	ns (min)
		N		25	ns (max)
		$V_A = +2.7$ to +3.6		6	ns (min)
t <sub>DIS</sub>	SCLK Falling Edge to SDATA High Impedance <sup>(3)</sup>	N/ A 75 / 5 05		25	ns (max)
		$V_A = +4.75$ to +5.25		5	ns (min)
t <sub>POWER-</sub> UP	Power-Up Time from Full Power-Down		1		μs

(1) Measured with the timing test circuit shown in Figure 2 and defined as the time taken by the output signal to cross 1.0V.

(2) Measured with the timing test circuit shown in Figure 2 and defined as the time taken by the output signal to cross 1.0V or 2.0V.

(3) t<sub>DIS</sub> is derived from the time taken by the outputs to change by 0.5V with the timing test circuit shown in Figure 2. The measured number is then adjusted to remove the effects of charging or discharging the output capacitance. This means that t<sub>DIS</sub> is the true bus relinquish time, independent of the bus loading.

## **Timing Diagrams**

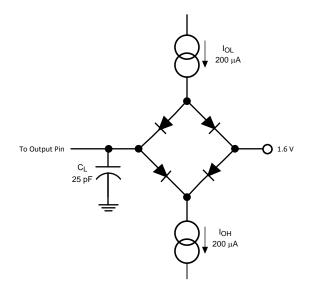
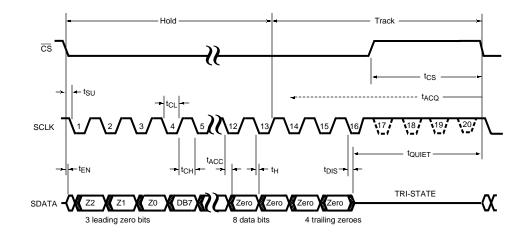


Figure 2. Timing Test Circuit







### **Specification Definitions**

- **ACQUISITION TIME** is the time required to acquire the input voltage. That is, it is time required for the hold capacitor to charge up to the input voltage. Acquisition time is measured backwards from the falling edge of CS when the signal is sampled and the part moves from track to hold. The start of the time interval that contains  $T_{ACQ}$  is the 13th rising edge of SCLK of the previous conversion when the part moves from hold to track. The user must ensure that the time between the 13th rising edge of SCLK and the falling edge of the next  $\overline{CS}$  is not less than  $T_{ACQ}$  to meet performance specifications.
- **APERTURE DELAY** is the time after the falling edge of  $\overline{CS}$  when the input signal is acquired or held for conversion.
- APERTURE JITTER (APERTURE UNCERTAINTY) is the variation in aperture delay from sample to sample. Aperture jitter manifests itself as noise in the output.
- **CONVERSION TIME** is the time required, after the input voltage is acquired, for the ADC to convert the input voltage to a digital word. This is from the falling edge of CS when the input signal is sampled to the 16th falling edge of SCLK when the SDATA output goes into TRI-STATE.
- **DIFFERENTIAL NON-LINEARITY (DNL)** is the measure of the maximum deviation from the ideal step size of 1 LSB.
- **DUTY CYCLE** is the ratio of the time that a repetitive digital waveform is high to the total time of one period. The specification here refers to the SCLK.
- **EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS)** is another method of specifying Signal-to-Noise and Distortion or SINAD. ENOB is defined as (SINAD 1.76) / 6.02 and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits.
- **FULL POWER BANDWIDTH** is a measure of the frequency at which the reconstructed output fundamental drops 3 dB below its low frequency value for a full scale input.
- **GAIN ERROR** is the deviation of the last code transition (111...110) to (111...111) from the ideal (V<sub>REF</sub> 1 LSB), after adjusting for offset error.
- **INTEGRAL NON-LINEARITY (INL)** is a measure of the deviation of each individual code from a line drawn from negative full scale (½ LSB below the first code transition) through positive full scale (½ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value.
- **INTERMODULATION DISTORTION (IMD)** is the creation of additional spectral components as a result of two sinusoidal frequencies being applied to the ADC input at the same time. It is defined as the ratio of the power in the second and third order intermodulation products to the sum of the power in both of the original frequencies. IMD is usually expressed in dB.

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# ADC081S101

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- **MISSING CODES** are those output codes that will never appear at the ADC outputs. The ADC081S101 is ensured not to have any missing codes.
- **OFFSET ERROR** is the deviation of the first code transition (000...000) to (000...001) from the ideal (i.e. GND + 1 LSB).
- SIGNAL TO NOISE RATIO (SNR) is the ratio, expressed in dB, of the rms value of the input signal to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or d.c.
- SIGNAL TO NOISE PLUS DISTORTION (S/N+D or SINAD) Is the ratio, expressed in dB, of the rms value of the input signal to the rms value of all of the other spectral components below half the clock frequency, including harmonics but excluding d.c.
- **SPURIOUS FREE DYNAMIC RANGE (SFDR)** is the difference, expressed in dB, between the desired signal amplitude to the amplitude of the peak spurious spectral component, where a spurious spectral component is any signal present in the output spectrum that is not present at the input and may or may not be a harmonic.
- **TOTAL HARMONIC DISTORTION (THD)** is the ratio, expressed in dB or dBc, of the rms total of the first five harmonic components at the output to the rms level of the input signal frequency as seen at the output. THD is calculated as

$$THD = 20 \cdot \log_{10} \sqrt{\frac{A_{f2}^2 + \dots + A_{f6}^2}{A_{f1}^2}}$$

where

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- $Af_1$  is the RMS power of the input frequency at the output
- $Af_2$  through  $Af_6$  are the RMS power in the first 5 harmonic frequencies
- **TOTAL UNADJUSTED ERROR** is the worst deviation found from the ideal transfer function. As such, it is a comprehensive specification which includes full scale error, linearity error, and offset error.
- **THROUGHPUT TIME** is the minimum time required between the start of two successive conversion. It is the acquisition time plus the conversion time.

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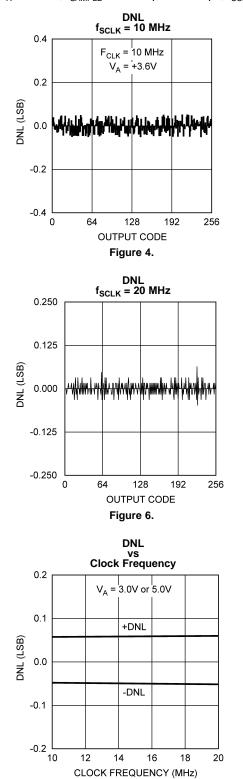
(1)





# Typical Performance Characteristics

 $T_A = +25^{\circ}C$ ,  $f_{SAMPLE} = 500$  ksps to 1 Msps,  $f_{SCLK} = 10$  MHz to 20 MHz,  $f_{IN} = 100$  kHz unless otherwise stated.



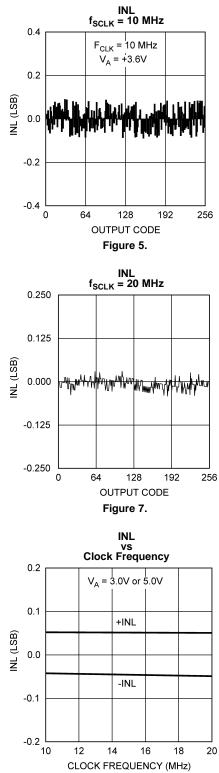
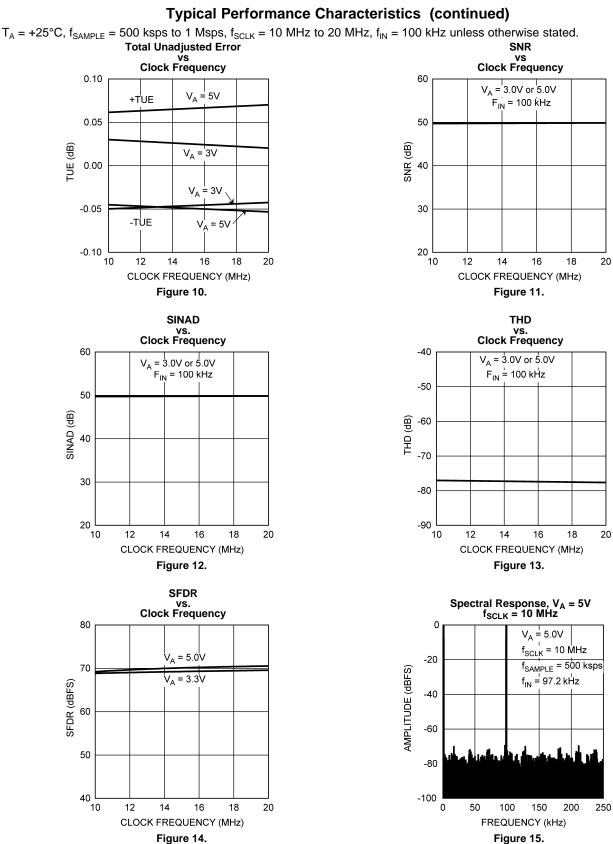


Figure 8.

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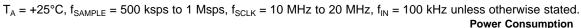


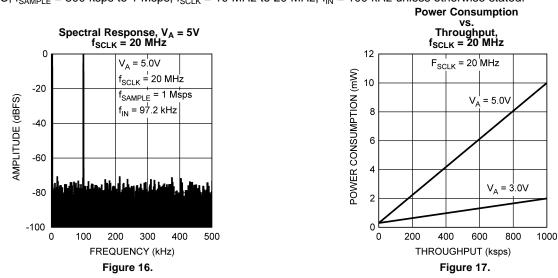
EXAS NSTRUMENTS

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## **APPLICATIONS INFORMATION**

### ADC081S101 Operation

The ADC081S101 is a successive-approximation analog-to-digital converter designed around a chargeredistribution digital-to-analog converter core. Simplified schematics of the ADC081S101 in both track and hold operation are shown in Figure 18 and Figure 19, respectively. In Figure 18, the device is in track mode: switch SW1 connects the sampling capacitor to the input, and SW2 balances the comparator inputs. The device is in this state until  $\overline{CS}$  is brought low, at which point the device moves to hold mode.

Figure 19 shows the device in hold mode: switch SW1 connects the sampling capacitor to ground, maintaining the sampled voltage, and switch SW2 unbalances the comparator. The control logic then instructs the charge-redistribution DAC to add or subtract fixed amounts of charge from the sampling capacitor until the comparator is balanced. When the comparator is balanced, the digital word supplied to the DAC is the digital representation of the analog input voltage. The device moves from hold mode to track mode on the 13th rising edge of SCLK.

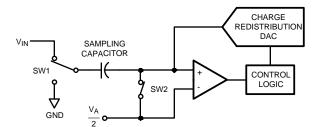


Figure 18. ADC081S101 in Track Mode

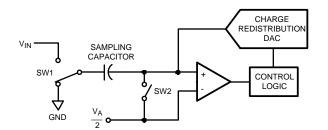


Figure 19. ADC081S101 in Hold Mode

## Using the ADC081S101

The serial interface timing diagram for the ADC is shown in Figure 3.  $\overline{CS}$  is chip select, which initiates conversions on the ADC and frames the serial data transfers. SCLK (serial clock) controls both the conversion process and the timing of serial data. SDATA is the serial data out pin, where a conversion result is found as a serial data stream.

Basic operation of the ADC begins with  $\overline{CS}$  going low, which initiates a conversion process and data transfer. Subsequent rising and falling edges of SCLK will be labelled with reference to the falling edge of  $\overline{CS}$ ; for example, "the third falling edge of SCLK" shall refer to the third falling edge of SCLK after  $\overline{CS}$  goes low.

At the fall of  $\overline{CS}$ , the SDATA pin comes out of TRI-STATE, and the converter moves from track mode to hold mode. The input signal is sampled and held for conversion on the falling edge of  $\overline{CS}$ . The converter moves from hold mode to track mode on the 13th rising edge of SCLK (see Figure 3). It is at this point that the interval for the T<sub>ACQ</sub> specification begins. At least 350ns must pass between the 13th rising edge of SCLK and the next falling edge of  $\overline{CS}$ . The SDATA pin will be placed back into TRI-STATE after the 16th falling edge of SCLK, or at the rising edge of  $\overline{CS}$ , whichever occurs first. After a conversion is completed, the quiet time t<sub>QUIET</sub> must be satisfied before bringing  $\overline{CS}$  low again to begin another conversion.



Sixteen SCLK cycles are required to read a complete sample from the ADC. The sample bits (including leading or trailing zeroes) are clocked out on falling edges of SCLK, and are intended to be clocked in by a receiver on subsequent falling edges of SCLK. The ADC will produce three leading zero bits on SDATA, followed by eight data bits, most significant first. After the data bits, the ADC will clock out four trailing zeros.

If  $\overline{CS}$  goes low before the rising edge of SCLK, an additional (fourth) zero bit may be captured by the next falling edge of SCLK.

#### Determining Throughput

Throughput depends on the frequency of SCLK and how much time is allowed to elapse between the end of one conversion and the start of another. At the maximum specified SCLK frequency, the maximum ensured throughput is obtained by using a 20 SCLK frame. As shown in Figure 3, the minimum allowed time between CS falling edges is determined by 1) 12.5 SCLKs for Hold mode, 2) the larger of two quantities: either the minimum required time for Track mode ( $t_{ACQ}$ ) or 2.5 SCLKs to finish reading the result and 3) 0, 1/2 or 1 SCLK padding to ensure an even number of SCLK cycles so there is a falling SCLK edge when CS next falls. For example, at the fastest rate for this family of parts, SCLK is 20MHz and 2.5 SCLKs are 125ns, so the minimum time between CS falling edges is calculated by:

12.5\*50ns + 350ns + 0.5\*50ns = 1000ns

(2)

(12.5 SCLKs +  $t_{ACQ}$  + 1/2 SCLK) which corresponds to a maximum throughput of 1MSPS. At the slowest rate for this family, SCLK is 1MHz. Using a 20-cycle conversion frame as shown in Figure 3 yields a 20µs time between CS falling edges for a throughput of 50KSPS.

It is possible, however, to use fewer than 20 clock cycles provided the timing parameters are met. With a 1MHz SCLK, there are 2500ns in 2.5 SCLK cycles, which is greater than  $t_{ACQ}$ . After the last data bit has come out, the clock will need one full cycle to return to a falling edge. Thus the total time between falling edges of CS is 12.5\*1µs +2.5\*1µs +1\*1µs=16µs which is a throughput of 62.5KSPS.

#### ADC081S101 Transfer Function

The output format of the ADC is straight binary. Code transitions occur midway between successive integer LSB values. The LSB width for the ADC is  $V_A/256$ . The ideal transfer characteristic is shown in Figure 20. The transition from an output code of 0000 0000 to a code of 0000 0001 is at 1/2 LSB, or a voltage of  $V_A/512$ . Other code transitions occur at steps of one LSB.

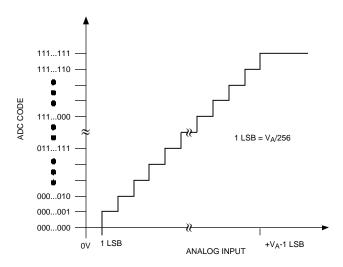


Figure 20. Ideal Transfer Characteristic



# **Typical Application Circuit**

A typical application of the ADC is shown in Figure 21. Power is provided in this example by the TI LP2950 lowdropout voltage regulator, available in a variety of fixed and adjustable output voltages. The power supply pin is bypassed with a capacitor network located close to the ADC. Because the reference for the ADC is the supply voltage, any noise on the supply will degrade device noise performance. To keep noise off the supply, use a dedicated linear regulator for this device, or provide sufficient decoupling from other circuitry to keep noise off the ADC supply pin. Because of the ADC's low power requirements, it is also possible to use a precision reference as a power supply to maximize performance. The four-wire interface is also shown connected to a microprocessor or DSP.

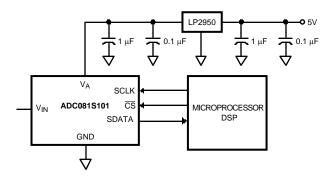


Figure 21. Typical Application Circuit

## Analog Input

An equivalent circuit for the ADC's input channel is shown in Figure 22. Diodes D1 and D2 provide ESD protection for the analog inputs. At no time should any input go beyond ( $V_A$  + 300 mV) or (GND - 300 mV), as these ESD diodes will begin conducting, which could result in erratic operation. For this reason, the ESD diodes should not be used to clamp the input signal.

The capacitor C1 in Figure 22 has a typical value of 4 pF, and is mainly the package pin capacitance. Resistor R1 is the on resistance of the multiplexer and track / hold switch, and is typically  $500\Omega$ . Capacitor C2 is the ADC sampling capacitor and is typically 26 pF. The ADC will deliver best performance when driven by a low-impedance source to eliminate distortion caused by the charging of the sampling capacitance. This is especially important when using the ADC to sample AC signals. Also important when sampling dynamic signals is an anti-aliasing filter.

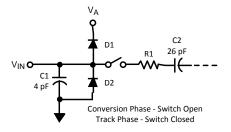


Figure 22. Equivalent Input Circuit

## **Digital Inputs and Outputs**

The ADC digital inputs (SCLK and  $\overline{CS}$ ) are not limited by the same absolute maximum ratings as the analog inputs. The digital input pins are instead limited to +5.25V with respect to GND, regardless of V<sub>A</sub>, the supply voltage. This allows the ADC to be interfaced with a wide range of logic levels, independent of the supply voltage.



#### **Modes of Operation**

The ADC has two possible modes of operation: <u>normal mode</u>, and shutdown mode. The ADC enters <u>normal</u> mode (and a conversion process is begun) when CS is pulled low. The device will enter shutdown mode if CS is pulled high before the tenth falling edge of SCLK after CS is pulled low, or will stay in normal mode if CS remains low. Once in shutdown mode, the device will stay there until CS is brought low again. By varying the ratio of time spent in the normal and shutdown modes, a system may trade-off throughput for power consumption, with a sample rate as low as zero.

#### Normal Mode

The fastest possible throughput is obtained by leaving the ADC in normal mode at all times, so there are no power-up delays. To keep the device in normal mode continuously,  $\overline{CS}$  must be kept low until after the 10th falling edge of SCLK after the start of a conversion (remember that a conversion is initiated by bringing  $\overline{CS}$  low).

If  $\overline{CS}$  is brought high after the 10th falling edge, but before the 16th falling edge, the device will remain in normal mode, but the current conversion will be aborted, and SDATA will return to TRI-STATE (truncating the output word).

Sixteen SCLK cycles are required to read all of a conversion word from the device. After sixteen SCLK cycles have elapsed, CS may be idled either high or low until the next conversion. If CS is idled low, it must be brought high again before the start of the next conversion, which begins when CS is again brought low.

After sixteen SCLK cycles, SDATA returns to TRI-STATE. Another conversion may be started, after t<sub>QUIET</sub> has elapsed, by bringing CS low again.

#### Shutdown Mode

Shutdown mode is appropriate for applications that either do not sample continuously, or it is acceptable to trade throughput for power consumption. When the ADC is in shutdown mode, all of the analog circuitry is turned off.

To enter shutdown mode, a conversion must be interrupted by bringing  $\overline{CS}$  back high anytime between the second and tenth falling edges of SCLK, as shown in Figure 23. Once  $\overline{CS}$  has been brought high in this manner, the device will enter shutdown mode; the current conversion will be aborted and SDATA will enter TRI-STATE. If  $\overline{CS}$  is brought high before the second falling edge of SCLK, the device will not change mode; this is to avoid accidentally changing mode as a result of noise on the  $\overline{CS}$  line.

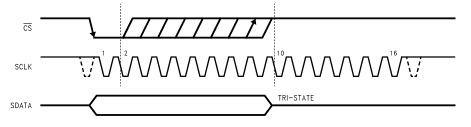


Figure 23. Entering Shutdown Mode

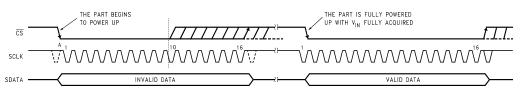


Figure 24. Entering Normal Mode

To exit shutdown mode, bring  $\overline{CS}$  back low. Upon bringing  $\overline{CS}$  low, the ADC will begin powering up (power-up time is specified in the ADC081S101 Timing Specifications table). This power-up delay results in the first conversion result being unusable. The second conversion performed after power-up, however, is valid, as shown in Figure 24.

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If CS is brought back high before the 10th falling edge of SCLK, the device will return to shutdown mode. This is done to avoid accidentally entering normal mode as a result of noise on the CS line. To exit shutdown mode and remain in normal mode, CS must be kept low until after the 10th falling edge of SCLK. The ADC will be fully powered-up after 16 SCLK cycles.

### **Power Management**

The ADC takes time to power-up, either after first applying V<sub>A</sub>, or after returning to normal mode from shutdown mode. This corresponds to one "dummy" conversion for any SCLK frequency within the specifications in this document. After this first dummy conversion, the ADC will perform conversions properly. Note that the touler time must still be included between the first dummy conversion and the second valid conversion.

When the  $V_A$  supply is first applied, the ADC may power up in either of the two modes: normal or shutdown. As such, one dummy conversion should be performed after start-up, as described in the previous paragraph. The part may then be placed into either normal mode or the shutdown mode, as described in Normal Mode and Shutdown Mode.

When the ADC is operated continuously in normal mode, the maximum ensured throughput is f<sub>SCLK</sub> / 20 at the maximum specified  $f_{SCLK}$ . Throughput may be traded for power consumption by running  $f_{SCLK}$  at its maximum specified rate and performing fewer conversions per unit time, raising the ADC CS line after the 10th and before the 15th fall of SCLK of each conversion. A plot of typical power consumption versus throughput is shown in the Typical Performance Characteristics section. To calculate the power consumption for a given throughput, multiply the fraction of time spent in the normal mode by the normal mode power consumption and add the fraction of time spent in shutdown mode multiplied by the shutdown mode power consumption. Note that the curve of power consumption vs. throughput is essentially linear. This is because the power consumption in the shutdown mode is so small that it can be ignored for all practical purposes.

### **Power Supply Noise Considerations**

The charging of any output load capacitance requires current from the power supply, V<sub>A</sub>. The current pulses required from the supply to charge the output capacitance will cause voltage variations on the supply. If these variations are large enough, they could degrade SNR and SINAD performance of the ADC. Furthermore, discharging the output capacitance when the digital output goes from a logic high to a logic low will dump current into the die substrate, which is resistive. Load discharge currents will cause "ground bounce" noise in the substrate that will degrade noise performance if that current is large enough. The larger the output capacitance, the more current flows through the die substrate and the greater is the noise coupled into the analog channel, degrading noise performance.

To keep noise out of the power supply, keep the output load capacitance as small as practical. It is good practice to use a 100 $\Omega$  series resistor at the ADC output, located as close to the ADC output pin as practical. This will limit the charge and discharge current of the output capacitance and improve noise performance. **REVISION HISTORY** 

Changes from Revision C (March 2013) to Revision D	Page
Changed sentence in the "Using the ADC081S101" section	12
Changes from Revision B (March 2013) to Revision C	Page



10-Dec-2020

# PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
ADC081S101 MWC	ACTIVE	WAFERSALE	YS	0	1	RoHS & Green	Call TI	Level-1-NA-UNLIM	-40 to 85		Samples
ADC081S101CIMF/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	X03C	Samples
ADC081S101CIMFX/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	X03C	Samples
ADC081S101CISD/NOPB	ACTIVE	WSON	NGF	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	X3C	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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STRUMENTS

## TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADC081S101CIMF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADC081S101CIMFX/ NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADC081S101CISD/NOPB	WSON	NGF	6	1000	178.0	12.4	2.8	2.5	1.0	8.0	12.0	Q1



# PACKAGE MATERIALS INFORMATION

9-Aug-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADC081S101CIMF/NOPB	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADC081S101CIMFX/ NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADC081S101CISD/NOPB	WSON	NGF	6	1000	210.0	185.0	35.0

# **DBV0006A**



# **PACKAGE OUTLINE**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



# **DBV0006A**

# **EXAMPLE BOARD LAYOUT**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **DBV0006A**

# **EXAMPLE STENCIL DESIGN**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

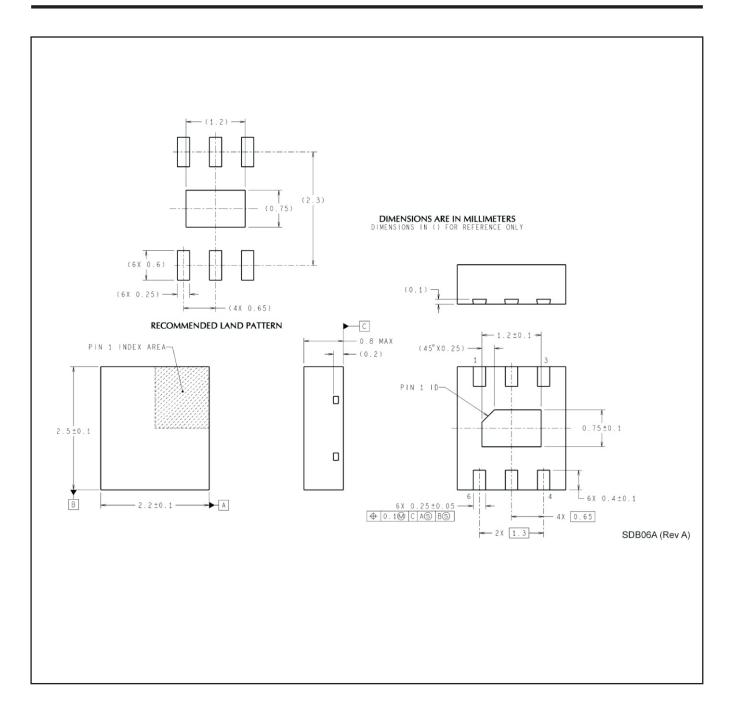
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



# **MECHANICAL DATA**

# NGF0006A





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